## Nch 40V 135A Power MOSFET

V <sub>DSS</sub>	40V
R <sub>DS(on)</sub> (Max.)	2.5mΩ
I <sub>D</sub>	±135A
P <sub>D</sub>	93W

# ● Features

- 1) Low on resistance
- 2) High Power small mold Package (HSMT8)
- 3) Pb-free plating; RoHS compliant
- 4) Halogen Free
- 5) 100% Rg and UIS tested

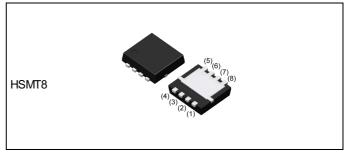
# Application

Switching

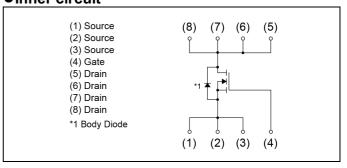
Motor drives

DC/DC converter

### Outline



# ●Inner circuit



Packaging specifications

- 1 dendeding operations					
	Packing	Embossed Tape			
	Reel size (mm)	330			
Туре	Tape width (mm)	12			
	Quantity (pcs)	3000			
	Taping code	TB1			
	Marking	G040CH			

# ● **Absolute maximum ratings** (T<sub>a</sub> = 25°C ,unless otherwise specified)

Para	meter	Symbol	Value	Unit
Drain - Source voltage		V <sub>DSS</sub>	40	V
Continuous dusin summent	Silicon limit (V <sub>GS</sub> =10V)	I <sub>D</sub> *1	±135	Α
Continuous drain current	$T_c = 25^{\circ}C (V_{GS} = 10V)$	I <sub>D</sub> *2	±40	Α
Pulsed drain current	•	I <sub>DP</sub> *3	±540	Α
Gate - Source voltage		$V_{GSS}$	±20	V
Avalanche current, single p	ulse	I <sub>AS</sub> *4	24	Α
Avalanche energy, single p	ulse	E <sub>AS</sub> *4	43	mJ
Dower dissinction		P <sub>D</sub> *2	93	W
Power dissipation		P <sub>D</sub> *5	2.4	W
Junction temperature		T <sub>j</sub>	175	°C
Operating junction and stor	age temperature range	T <sub>stg</sub>	-55 to +175	°C

# ●Thermal resistance

Parameter	Symbol	Values			l limit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub> *2	-	-	1.6	°C/W
Thermal resistance, junction - ambient	R <sub>thJA</sub> *5	-	-	62.5	°C/W

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

Daramatar	Cymah al	Conditions	Values			Lleit	
Parameter	Symbol Conditions -		Min.	Тур.	Max.	Unit	
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V$ , $I_D = 1mA$	40	-	-	V	
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	I <sub>D</sub> = 1mA referenced to 25°C	-	21	-	mV/°C	
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 40V, V <sub>GS</sub> = 0V	-	-	2	μA	
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±200	nA	
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 1mA$	2.0	-	4.0	V	
Gate threshold voltage temperature coefficient	$\frac{\Delta  V_{GS(th)}}{\Delta  T_j}$	I <sub>D</sub> = 1mA referenced to 25°C	-	-5.7	-	mV/°C	
Static drain - source	D *6	V <sub>GS</sub> = 10V, I <sub>D</sub> = 40A	-	2.1	2.5	0	
on - state resistance	R <sub>DS(on)</sub> *6	V <sub>GS</sub> = 6V, I <sub>D</sub> = 20A	-	3.4	4.7	mΩ	
Gate resistance	$R_{G}$	-	-	1.6	-	Ω	
Forward Transfer Admittance	Y <sub>fs</sub>  *6	V <sub>DS</sub> = 5V, I <sub>D</sub> = 20A	18	-	-	S	

<sup>\*1</sup> Limited by silicon chip capability.

<sup>\*2</sup>  $T_c$ =25°C, Limited only by maximum temperature allowed.

<sup>\*3</sup> Pw  $\leq$  10 $\mu$ s , Duty cycle  $\leq$  1%

<sup>\*4</sup> L  $\simeq$  0.1mH, V<sub>DD</sub> = 20V, R<sub>G</sub> = 25 $\Omega$ , Starting T<sub>j</sub> = 25 $^{\circ}$ C Fig.3-1,3-2

<sup>\*5</sup> Mounted on a Cu board (40×40×0.8mm)

<sup>\*6</sup> Pulsed

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

Dorameter	Cumbal	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	1930	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 20V	-	1070	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	1	90	1	
Turn - on delay time	t <sub>d(on)</sub> *6	V <sub>DD</sub> ≈ 20V,V <sub>GS</sub> = 10V	1	24	1	
Rise time	<b>t</b> <sub>r</sub> *6	I <sub>D</sub> = 20A	1	21	1	no
Turn - off delay time	t <sub>d(off)</sub> *6	$R_L \simeq 1\Omega$	-	45	-	ns
Fall time	t <sub>f</sub> *6	$R_G = 10\Omega$	-	25	-	

# ● Gate charge characteristics (T<sub>a</sub> = 25°C)

Davanastav	Cymada a l	Values				l lait	
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
Total gate charge	O *6		V <sub>GS</sub> = 10V	-	32.0	-	
Total gate charge	$Q_g^{*6}$	V <sub>DD</sub> ≃ 20V		-	19.7	-	»C
Gate - Source charge	Q <sub>gs</sub> *6	I <sub>D</sub> = 40A	V <sub>GS</sub> = 6V	-	8.4	-	nC
Gate - Drain charge	Q <sub>gd</sub> *6			-	6.3	-	

# ●Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Values			Unit
raiametei	Symbol	Conditions	Min.	Тур.	Max.	Offic
Continuous forward current	I <sub>S</sub> *2		1	-	40	Α
Pulse forward current	I <sub>SP</sub> *3	-	-	-	540	Α
Forward voltage	V <sub>SD</sub> *6	V <sub>GS</sub> = 0V, I <sub>S</sub> = 40A	-	-	1.2	V
Reverse recovery time	t <sub>rr</sub> *6	I <sub>S</sub> = 40A, V <sub>GS</sub> =0V	-	43.7	-	ns
Reverse recovery charge	Q <sub>rr</sub> *6	di/dt = 100A/µs	-	41.5	-	nC

Power Dissipation: P<sub>D</sub>/P<sub>Dmax</sub>. [%]

## • Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

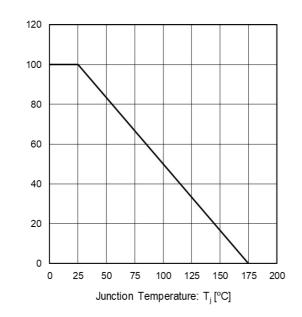
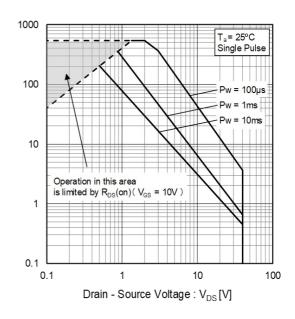


Fig.2 Maximum Safe Operating Area



Drain Current : I<sub>D</sub> [A]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

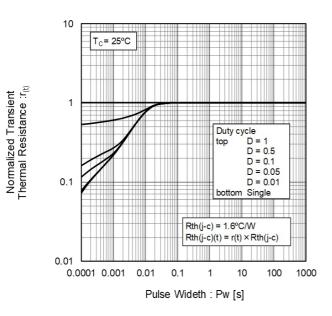
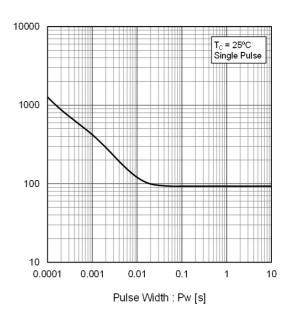


Fig.4 Single Pulse Maximum Power Dissipation



Peak Transient Power: P[W]

Drain Current : I<sub>□</sub> [A]

Normalized Breakdown Voltage :  $V_{(BR)DSS}$ 

### • Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)

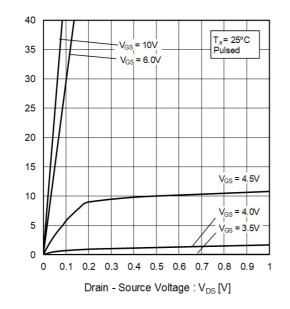


Fig.6 Typical Output Characteristics(II)

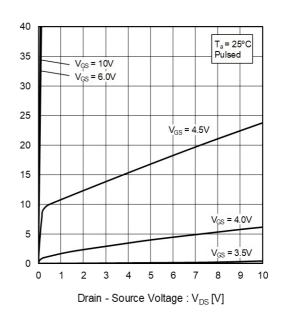


Fig.7 Normalized Breakdown Voltage vs. Junction Temperature

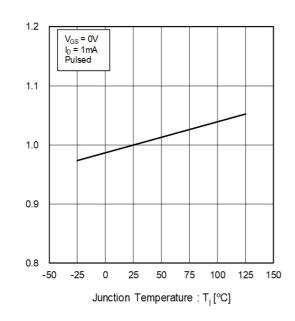
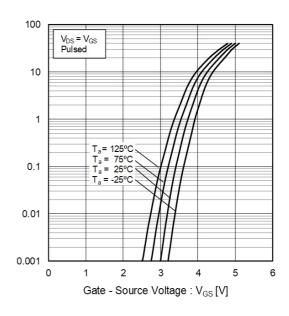


Fig.8 Typical Transfer Characteristics



Drain Current : I<sub>D</sub> [A]

Gate Threshold Voltage: VGS(th) [V]

## • Electrical characteristic curves

Fig.9 Gate Threshold Voltage vs.
Junction Temperature

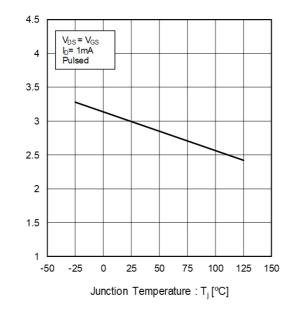


Fig.10 Forward Transfer Admittance vs.
Drain Current

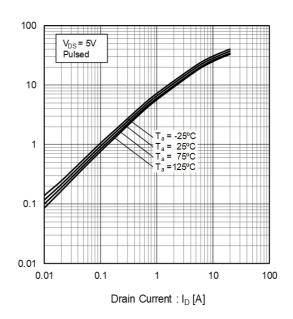


Fig.11 Drain Current Derating Curve

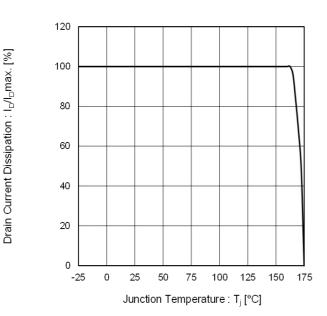
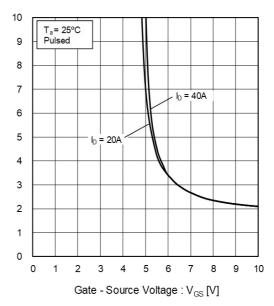


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



Static Drain - Source On-State Resistance

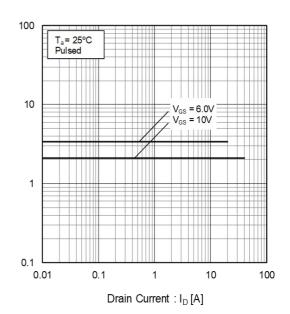
Forward Transfer Admittance : Y<sub>fs</sub> [S]

## • Electrical characteristic curves

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

5 V<sub>GS</sub> = 10V Pulsed Static Drain - Source On-State Resistance 4 3 I<sub>D</sub> = 40A 2 1 0 -50 -25 50 75 100 125 150 0 Junction Temperature : Ti [°C]

Fig.14 Static Drain - Source On - State Resistance vs. Drain Current (I)



Static Drain - Source On-State Resistance :  $R_{\mathrm{DS}(\sigma\eta)}$  [m $\Omega$ ]

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)

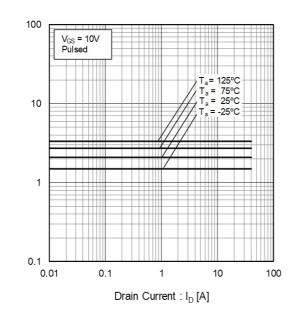
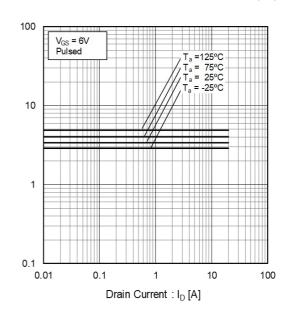


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)



Static Drain - Source On-State Resistance

 $:R_{DS(on)}\left[ m\Omega \right]$ 

Static Drain - Source On-State Resistance

Capacitance : C [pF]

## • Electrical characteristic curves

Fig.17 Typical Capacitances vs.

Drain - Source Voltage

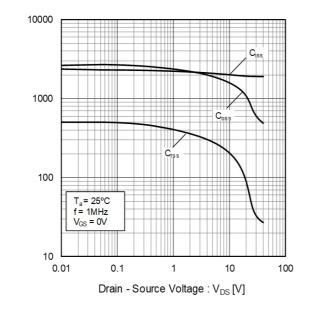


Fig.18 Switching Characteristics

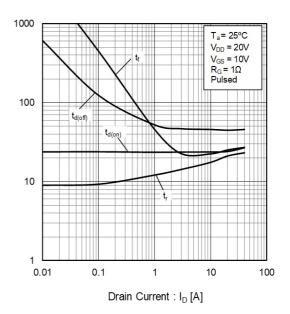


Fig.19 Typical Gate Charge

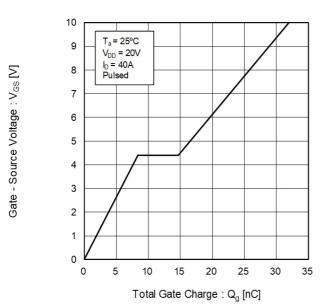
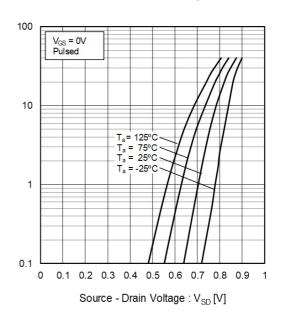


Fig.20 Source Current vs.

Source Drain Voltage



Source Current : Is [A]

Switching Time: t [ns]

## Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

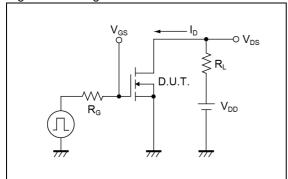


Fig.1-2 Switching Waveforms

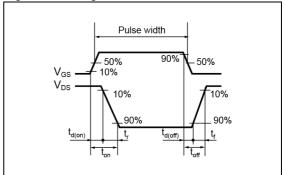


Fig.2-1 Gate Charge Measurement Circuit

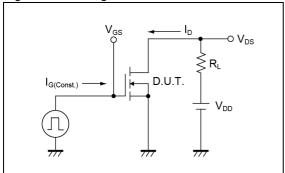


Fig.2-2 Gate Charge Waveform

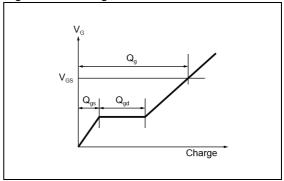


Fig.3-1 Avalanche Measurement Circuit

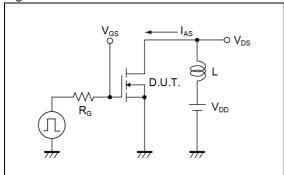
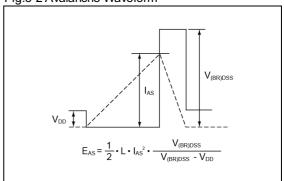


Fig.3-2 Avalanche Waveform

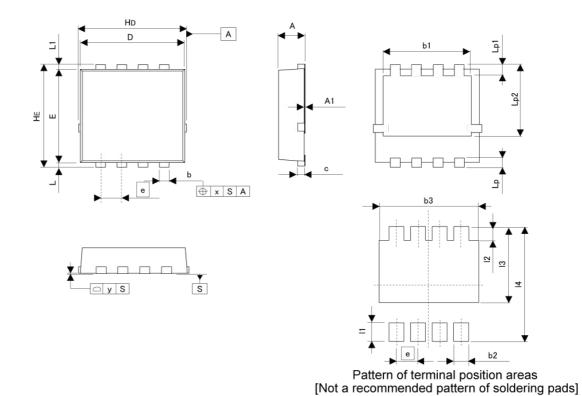


### Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

# Dimensions

HSMT8 (TB1) ( 3.3x3.3 )



DIM	MILIME	TERS	INCI	HES
DIIVI	MIN	MAX	MIN	MAX
Α	0.65	0.85	0.026	0.033
A1	0.00	0.10	0.000	0.004
b	0.24	0.42	0.009	0.017
b1	2.29	2.69	0.090	0.106
С	0.05	0.25	0.002	0.010
D	3.05	3.25	0.120	0.128
E	2.95	3.15	0.116	0.124
е	0.	65	0.026	
HD	3.20	3.40	0.126	0.134
HE	3.20	3.40	0.126	0.134
L	0.05	0.23	0.002	0.009
L1	0.05	0.23	0.002	0.009
Lp	0.20	0.60	0.008	0.024
Lp1	0.20	0.60	0.008	0.024
Lp2	1.83	2.63	0.072	0.104
х	-	0.10	-	0.004
у	-	0.10	-	0.004

DIM	MILIMETERS		INCHES		
Dilvi	MIN	MAX	MIN	MAX	
b2	-	0.52	1-1	0.020	
b3	-	2.79	-	0.110	
l1	141	0.70	-	0.028	
12		0.70	-	0.028	
13	TEX	2.53	(2)	0.100	
14	-	3.60	-	0.142	

Dimension in mm/inches



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JÁPAN	USA	EU	CHINA
CLASSⅢ	CL A CC TT	CLASS II b	CL ACCIII
CLASSIV	CLASSⅢ	CLASSⅢ	CLASSⅢ

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  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### **Precautions Regarding Application Examples and External Circuits**

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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